

UTC UNISONIC TECHNOLOGIES CO., LTD

MGBR20S50C

Preliminary

DIODE

DUAL MOS GATED BARRIER RECTIFIER

DESCRIPTION

The UTC MGBR20S50C is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

The UTC MGBR20S50C suitable for supply applications.

FEATURES

* Super low forward voltage drop

* High switching speed

SYMBOL

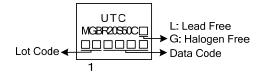
ORDERING INFORMATION

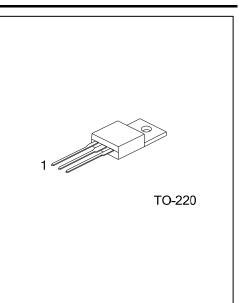
Ordering Number		Package	Pin Assignment			Booking	
Lead Free	Halogen Free	Гаскауе	1	2	3	Packing	
MGBR20S50CL-TA3-T	MGBR20S50CG-TA3-T	TO-220	Α	К	А	Tube	

Note: Pin Assignment: A: Anode K: Cathode

MGBR20S50CL- <u>TA3</u> -T	(1)Packing Type	(1) T: Tube
	(2)Package Type	(2) TA3: TO-220
	(3)Green Package	(3) L: Lead Free, G: Halogen Free and Lead Free

MARKING





■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

T of capacitatice load, defate current by A	2070.			
PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V _{RM}	50	V
Working Peak Reverse Voltage		V _{RWM}	50	V
Peak Repetitive Reverse Voltage		V _{RRM}	50	V
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50%	Per Leg		10	А
Duty Cycle	Total	I _O	20	А
Peak Forward Surge Current - 1/2 60hz		I _{FSM}	180	А
Peak Repetitive Reverse Surge Current	(2uS-1Khz)	I _{RRM}	2	А
Maximum Rate of Voltage Change (at Rated V _R)		dv/dt	10000	V/µS
Operating Junction Temperature		TJ	-65~+150	°C
Storage Junction Temperature		T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ _{JC}	2	°C/W

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.50mA	50			V
Forward Voltage	VEM	I _F =10A, T _J =25°C			0.50	V
		I _F =10A, T _J =125°C			0.45	V
Reverse Current (Note 1)	RM	V _R =50V, T _J =25°C			500	μA
		V _R =50V, T _J =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.



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